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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## MOS FIELD EFFECT TRANSISTOR NP34N055HLE, NP34N055ILE, NP34N055SLE

### SWITCHING N-CHANNEL POWER MOSFET

#### **DESCRIPTION**

These products are N-Channel MOS Field Effect Transistors designed for high current switching applications.

#### **FEATURES**

- Channel temperature 175 degree rated
- Super low on-state resistance

 $R_{DS(on)1}$  = 18  $m\Omega$  MAX. (Vgs = 10 V, Ip = 17 A)

 $R_{DS(on)2} = 22 \text{ m}\Omega \text{ MAX.} (V_{GS} = 5 \text{ V}, I_{D} = 17 \text{ A})$ 

- Low Ciss : Ciss = 2000 pF TYP.
- · Built-in gate protection diode

#### **★ ORDERING INFORMATION**

PART NUMBER	PACKAGE
NP34N055HLE	TO-251 (JEITA) / MP-3
NP34N055ILE Note	TO-252 (JEITA) / MP-3Z
NP34N055SLE	TO-252 (JEDEC) / MP-3ZK

(TO-251)

Note Not for new design.

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage	VDSS	55	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	ID(DC)	±34	Α
Drain Current (Pulse) Note1	ID(pulse)	±136	Α
Total Power Dissipation (T <sub>A</sub> = 25°C)	Рт	1.2	W
Total Power Dissipation (Tc = 25°C)	Рт	88	W
Single Avalanche Current Note2	las	34 / 27 / 10	Α
Single Avalanche Energy Note2	Eas	11 / 72 / 100	mJ
Channel Temperature	Tch	175	°C
Storage Temperature	T <sub>stg</sub>	-55 to + 175	°C

**Notes 1.** PW  $\leq$  10  $\mu$  s, Duty Cycle  $\leq$  1%

**2.** Starting T<sub>ch</sub> = 25°C, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V (See Figure 4.)

#### THERMAL RESISTANCE

Channel to Case Thermal Resistance	$R_{th(ch-C)}$	1.70	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	125	°C/W

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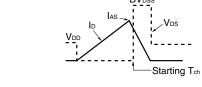
#### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

		1	_			
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 55 V, V <sub>GS</sub> = 0 V			10	μΑ
Gate Leakage Current	Igss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μΑ
Gate to Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.5	2	2.5	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 17 A	9	19		S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 17 A		14	18	mΩ
	RDS(on)2	V <sub>GS</sub> = 5 V, I <sub>D</sub> = 17 A		17	22	mΩ
	RDS(on)3	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 17 A		18	24	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 25 V		2000	3000	pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		250	380	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		130	230	pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 28 V, I <sub>D</sub> = 17 A		17	37	ns
Rise Time	tr	V <sub>GS</sub> = 10 V		11	28	ns
Turn-off Delay Time	<b>t</b> d(off)	R <sub>G</sub> = 1 Ω		57	110	ns
Fall Time	tf			9	23	ns
Total Gate Charge	Q <sub>G1</sub>	V <sub>DD</sub> = 44 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 34 A		41	72	nC
	Q <sub>G2</sub>	V <sub>DD</sub> = 44 V		23	35	nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = 5 V		7		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 34 A		12		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 34 A, V <sub>GS</sub> = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 34 A, VGS = 0 V		42		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		58		nC

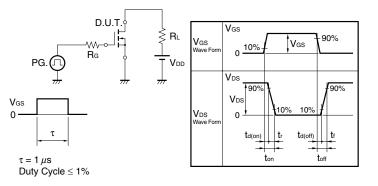
Note Pulsed

#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

# $V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{GS} = 20 \rightarrow 0 \text{ V}$ $V_{DS} = 20 \rightarrow 0 \text{ V}$



#### **TEST CIRCUIT 2 SWITCHING TIME**



#### **TEST CIRCUIT 3 GATE CHARGE**

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \ \underline{m} A \\ \hline W \\ \hline \end{array} \begin{array}{c} R_L \\ \hline \end{array}$$

#### TYPICAL CHARACTERISTICS (TA = 25°C)



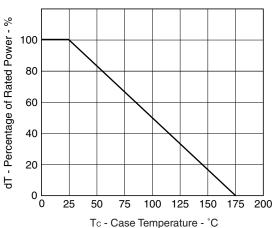


Figure 3. FORWARD BIAS SAFE OPERATING AREA

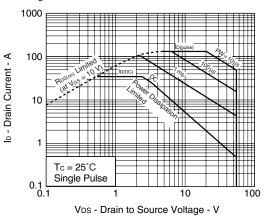


Figure 2. TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

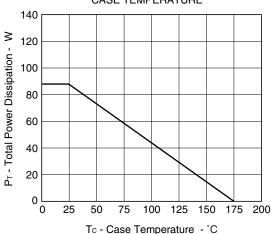


Figure4. SINGLE AVALANCHE ENERGY DERATING FACTOR

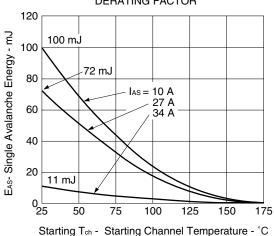


Figure 5. TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

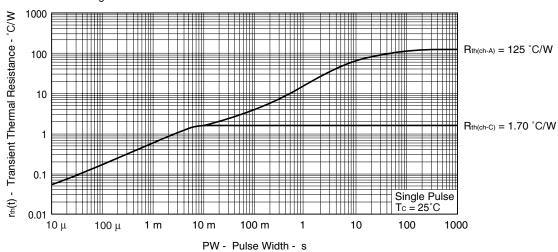


Figure 6. FORWARD TRANSFER CHARACTERISTICS

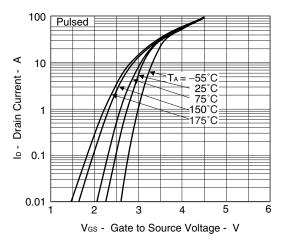


Figure 8. FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

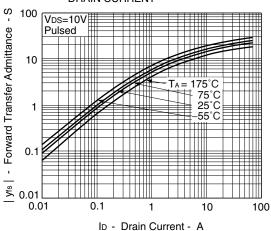


Figure 10. DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT 40 Pulsed

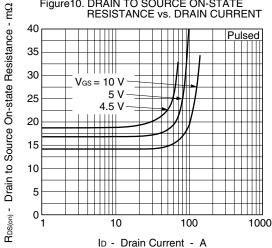
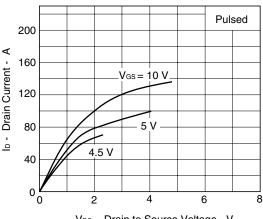


Figure 7. DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



VDS - Drain to Source Voltage - V

Figure 9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

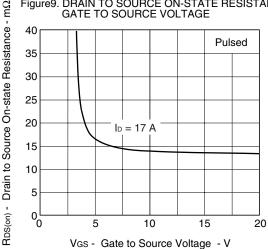
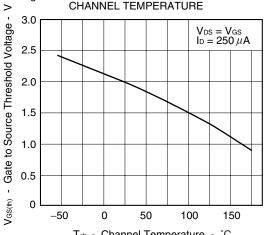


Figure 11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



Tch - Channel Temperature - °C



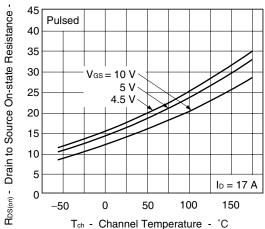


Figure 14. CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

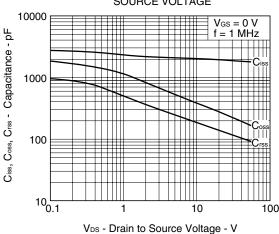


Figure 16. REVERSE RECOVERY TIME vs. DRAIN CURRENT

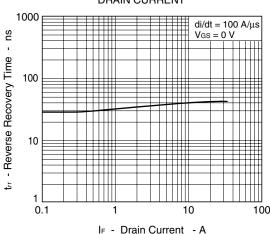


Figure 13. SOURCE TO DRAIN DIODE FORWARD VOLTAGE

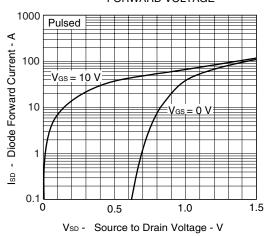


Figure 15. SWITCHING CHARACTERISTICS

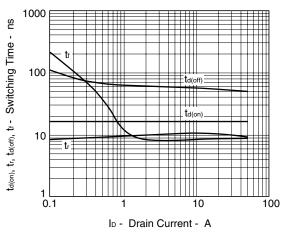
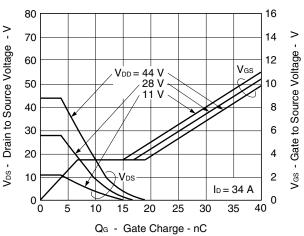
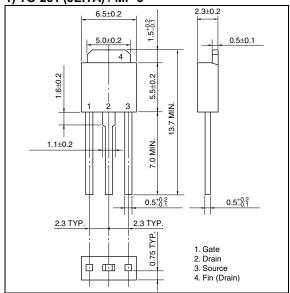


Figure 17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS

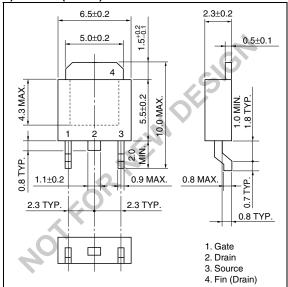


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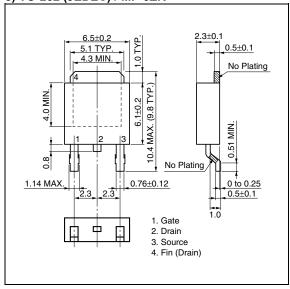




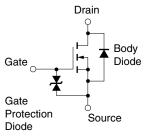
#### 2) TO-252 (JEITA) / MP-3Z



#### 3) TO-252 (JEDEC) / MP-3ZK



#### **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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